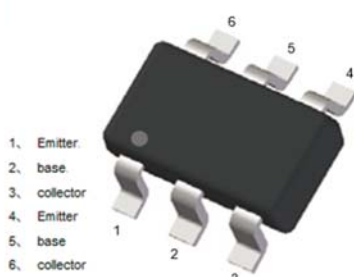
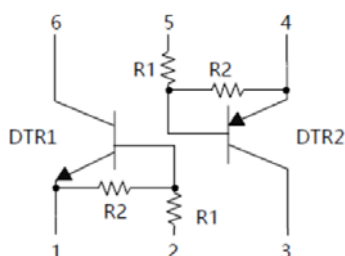


Dual NPN+PNP Digital Transistors (Built-in Resistors)



Features

- Moisture sensitivity level 1
- Halogen free and RoHS compliant
- Surface mount package ideally suited for automatic Insertion

Application

- Signal amplification
- Switching circuit

Mechanical data

- **Package:** SOT-363S
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102

■ Maximum Ratings ($T_a=25^{\circ}\text{C}$ Unless otherwise specified)

DTR1-NPN

Item	Symbol	Unit	Conditions	Value
Device marking code				D17
Collector-base voltage	V_{CC}	V		50
Collector-emitter voltage	V_{IN}	V		-10 to +40
Collector current	I_O	mA		100
Power dissipation	P_D	mW		150
Operation junction temperature	T_J	$^{\circ}\text{C}$		-55 to +150
Storage temperature	T_{STG}	$^{\circ}\text{C}$		-55 to +150

DTR2-PNP

Item	Symbol	Unit	Conditions	Value
Collector-base voltage	V_{CC}	V		-50
Collector-emitter voltage	V_{IN}	V		-40 to +10
Collector current	I_O	mA		-30
Power dissipation	P_D	mW		150
Operation junction temperature	T_J	$^{\circ}\text{C}$		-55 to +150
Storage temperature	T_{STG}	$^{\circ}\text{C}$		-55 to +150



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■ Electrical Characteristics (T_a=25°C Unless otherwise specified)

DTR1-NPN

Item	Symbol	Unit	Conditions	Min	Typ	Max
Input voltage	V _{I(off)}	V	V _{CC} =5V, I _O =100uA	0.5		
	V _{I(on)}	V	V _O =0.3V, I _O =2mA			4.0
Output voltage	V _{O(on)}	V	I _O / I _I = 10mA/0.5 mA			0.3
Output current	I _{O(off)}	uA	V _{CC} =50V, V _I =0			0.5
DC current gain	G _I		V _O =5V, I _O =5mA	56		
Input resistance	R ₁	kΩ		33	47	61
Resistance ratio	R ₂ /R ₁			0.37	0.47	0.57
Transition frequency	f _T	MHz	V _O =10V, I _O =5mA, f=100MHz		250	

DTR2-PNP

Item	Symbol	Unit	Conditions	Min	Typ	Max
Input voltage	V _{I(off)}	V	V _{CC} =-5V, I _O =-100uA			-0.8
	V _{I(on)}	V	V _O =-0.3V, I _O =-2mA	-4.0		
Output voltage	V _{O(on)}	V	I _O / I _I = -10mA/-0.5 mA			-0.3
Output current	I _{O(off)}	uA	V _{CC} =-50V, V _I =0			-0.5
DC current gain	G _I		V _O =-5V, I _O =-5mA	56		
Input resistance	R ₁	kΩ		33	47	61
Resistance ratio	R ₂ /R ₁			0.37	0.47	0.57
Transition frequency	f _T	MHz	V _O =-10V, I _O =-5mA, f=100MHz		250	

■ Thermal Characteristics

Parameter	Symbol	Unit	Value
Thermal resistance, junction-to-ambient	R _{θJ-A} ⁽¹⁾	°C/W	834
Thermal resistance, junction-to-case	R _{θJ-C} ⁽¹⁾	°C/W	667

Note:(1)Device mounted on PCB, single-sided copper, with standard footprint.

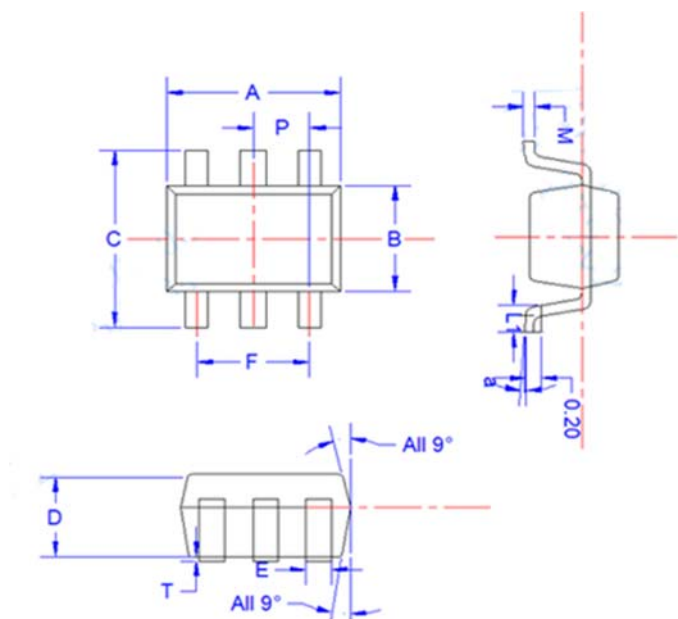
■ Ordering Information

Preferred P/N	Packing code	Unit weight(g)	Minimum package(pcs)	Inner box quantity(pcs)	Outer carton quantity(pcs)	Delivery mode
UMD17NS	F2	Approximate 0.009	3000	30000	120000	7" reel
UMD17NS	F3	Approximate 0.009	10000	/	210000	7" reel



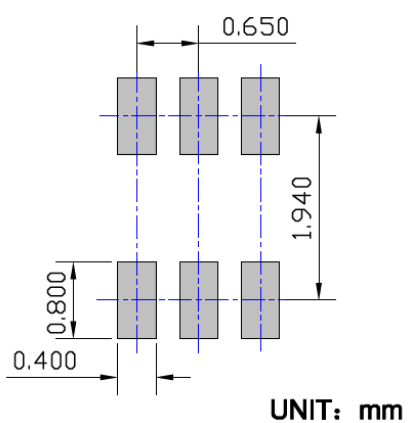
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■ Outline Dimensions



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
E	0.15	0.25	0.35
B	1.15	1.25	1.35
C	2.00	2.10	2.20
P	0.650BSC		
A	1.80	2.00	2.20
T	0.00	0.05	0.100
D	0.90	0.95	1.00
L1	0.20	0.30	0.40
a	4°±4°		
M	0.10	0.15	0.25

■ Suggested Pad Layout





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